



# Schottky Diode

$V_{RRM} = 100\text{ V}$   
 $I_{FAV} = 2 \times 15\text{ A}$   
 $V_F = 0.64\text{ V}$

High Performance Schottky Diode  
Low Loss and Soft Recovery  
Common Cathode

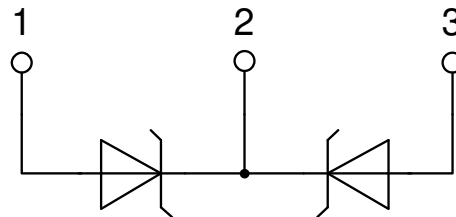
Part number

**DSSK28-01AS**

Marking on Product: *DSSK28-01AS*



Backside: cathode



### Features / Advantages:

- Very low  $V_f$
- Extremely low switching losses
- Low  $I_{rm}$  values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

### Package: TO-263 (D2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

### Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics).



Schottky				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
$V_{RSM}$	max. non-repetitive reverse blocking voltage					100	V
$V_{RRM}$	max. repetitive reverse blocking voltage					100	V
$I_R$	reverse current, drain current	$V_R = 100\text{ V}$		$T_{VJ} = 25^\circ\text{C}$		500	$\mu\text{A}$
		$V_R = 100\text{ V}$		$T_{VJ} = 125^\circ\text{C}$		5	mA
$V_F$	forward voltage drop	$I_F = 15\text{ A}$		$T_{VJ} = 25^\circ\text{C}$		0.82	V
		$I_F = 30\text{ A}$				0.95	V
		$I_F = 15\text{ A}$		$T_{VJ} = 125^\circ\text{C}$		0.64	V
		$I_F = 30\text{ A}$				0.78	V
$I_{FAV}$	average forward current	$T_C = 160^\circ\text{C}$	rectangular	$T_{VJ} = 175^\circ\text{C}$		15	A
$V_{F0}$	threshold voltage	} for power loss calculation only				0.43	V
$r_F$	slope resistance					8.6	m $\Omega$
$R_{thJC}$	thermal resistance junction to case					1.4	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.25			K/W
$P_{tot}$	total power dissipation			$T_C = 25^\circ\text{C}$		105	W
$I_{FSM}$	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$		$T_{VJ} = 45^\circ\text{C}$		230	A
$C_J$	junction capacitance	$V_R = 12\text{ V}$ $f = 1\text{ MHz}$		$T_{VJ} = 25^\circ\text{C}$		289	pF



Package TO-263 (D2Pak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			35	A
$T_{VJ}$	virtual junction temperature		-55		175	°C
$T_{op}$	operation temperature		-55		150	°C
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				1.5		g
$F_C$	mounting force with clip		20		60	N

**Product Marking**



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSSK28-01AS-TRL	DSSK28-01AS	Tape & Reel	800	494119
Alternative	DSSK28-01AS-TUB	DSSK28-01AS	Tube	50	492280

Similar Part	Package	Voltage class
DSSK30-01A	TO-247AD (3)	100
DSA30C100PB	TO-220AB (3)	100
DSA30C100PN	TO-220ABFP (3)	100
DSA30C100HB	TO-247AD (3)	100

DSA30C100QB	TO-3P (3)	100
DSA60C100PB	TO-220AB (3)	100
DSA50C100HB	TO-247AD (3)	100

**Equivalent Circuits for Simulation** \* on die level  $T_{VJ} = 175^{\circ}C$



Schottky

$V_{0\ max}$	threshold voltage	0.43	V
$R_{0\ max}$	slope resistance *	5.4	mΩ

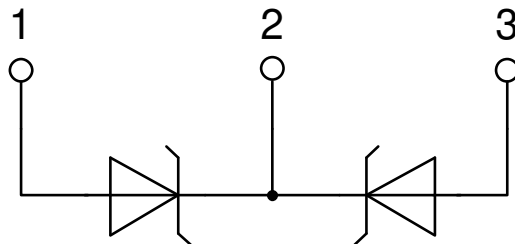


**Outlines TO-263 (D2Pak)**



Dim.	Millimeter		Inches	
	min	max	min	max
A	4.06	4.83	0.160	0.190
A1	typ. 0.10		typ. 0.004	
A2	2.41		0.095	
b	0.51	0.99	0.020	0.039
b2	1.14	1.40	0.045	0.055
c	0.40	0.74	0.016	0.029
c2	1.14	1.40	0.045	0.055
D	8.38	9.40	0.330	0.370
D1	8.00	8.89	0.315	0.350
D2	2.5		0.098	
E	9.65	10.41	0.380	0.410
E1	6.22	8.50	0.245	0.335
e	2,54 BSC		0,100 BSC	
e1	4.28		0.169	
H	14.61	15.88	0.575	0.625
L	1.78	2.79	0.070	0.110
L1	1.02	1.68	0.040	0.066
W	typ. 0.02	0.040	typ. 0.0008	0.002

*All dimensions conform with and/or within JEDEC standard.*



**Schottky**

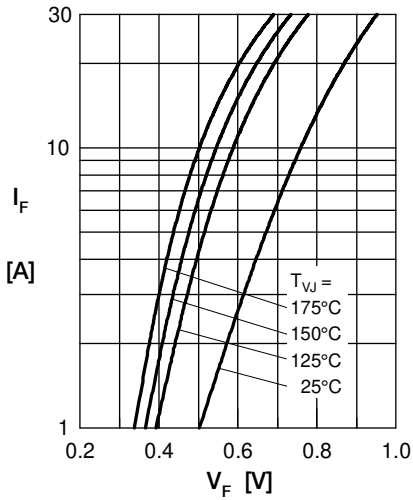


Fig. 1 Maximum forward voltage drop characteristics

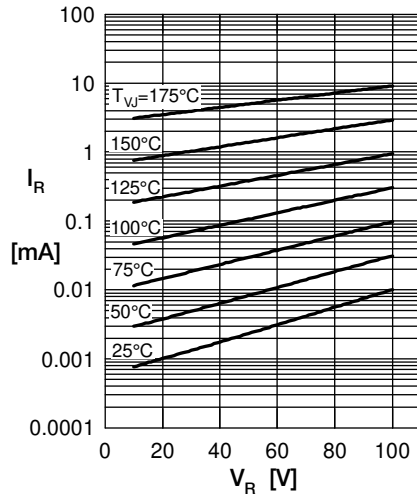


Fig. 2 Typ. reverse current  $I_R$  vs. reverse voltage  $V_R$

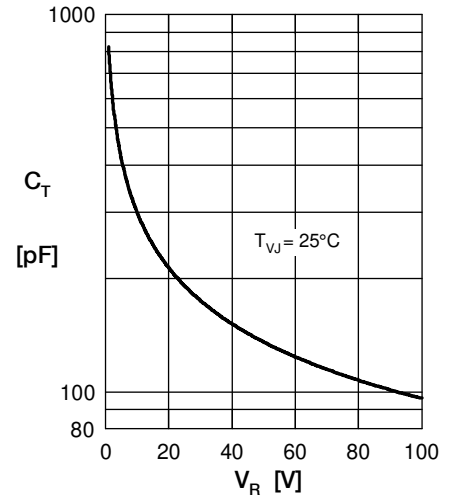


Fig. 3 Typ. junction capacitance  $C_T$  vs. reverse voltage  $V_R$

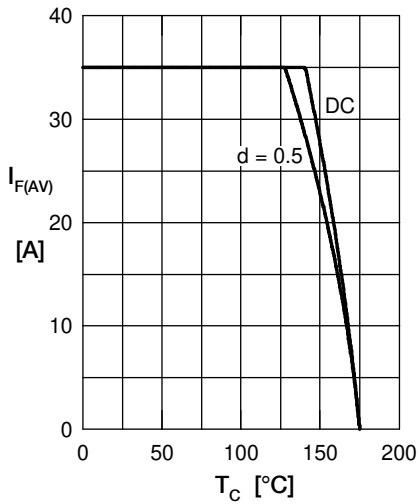


Fig. 4 Average forward current  $I_{F(AV)}$  vs. case temp.  $T_C$

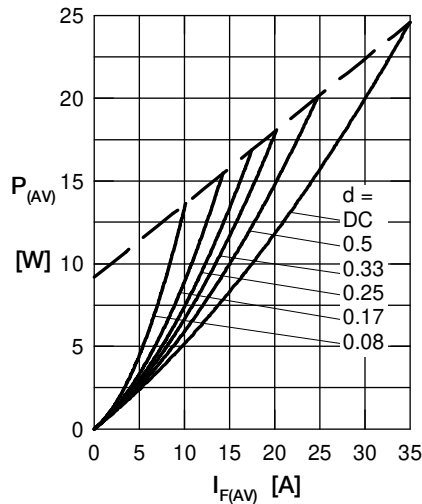


Fig. 5 Forward power loss characteristics

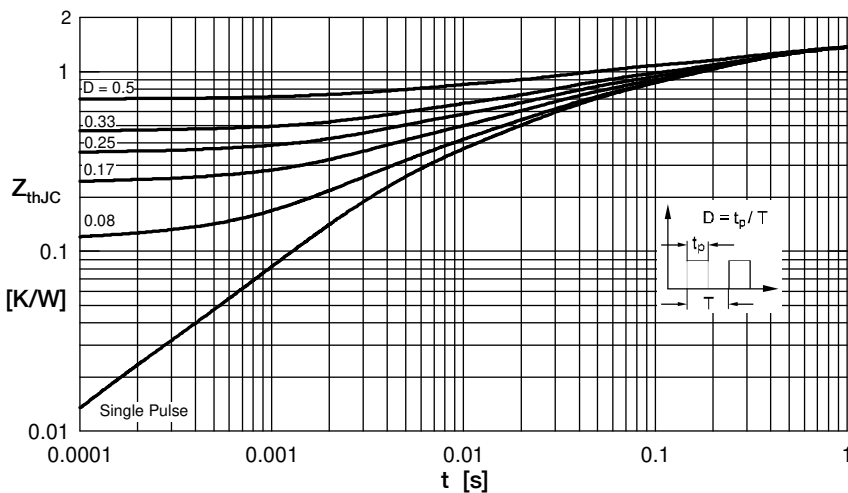


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode